NSN 5961-01-249-8304

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-249-8304 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Burn in and hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 100.0 repetitive peak off-state voltage **Current Rating Per Characteristic:** 0.35 amperes forward current, total rms horsepower metric and 25.00 amperes peak forward surge current absolute and 0.50 amperes repetitive peak forward current torr **Power Rating Per Characteristic:** 10.0 watts small-signal input power, common-collector blank and 0.05 watts any acceptable universal **Maximum Operating Tempurature Per Measurement Point:** 100.0 degrees celsius junction **Test Data Document:** 53711-5882634 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: